

New *Single-Phase* Concepts: S1 & S2*

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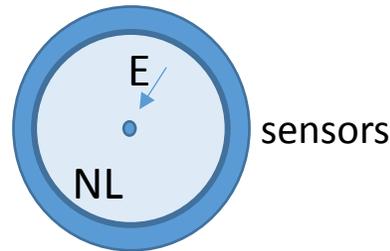
Remark: see two talks on *dual-phase* novelties by **Chepel** and **Martinez Lema**

* <http://arxiv.org/abs/2203.01774>
<https://doi.org/10.1088/1748-0221/17/08/P08002>

Why single phase?

- To overcome current expected problems with large dual-phase dets':
 - liquid-gas interface instabilities, gas gap variations, electron extraction efficiency
- Only single-phase can be “**face-to-face**” and “**horizontal**”:
 - Half of HV for equal field; avoids effects of sporadic bubbles

- “**Radial geometry**” possible

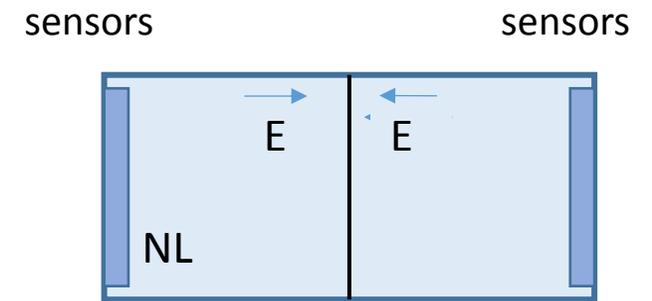


- New concepts, technologies:

Expected: High photo-yields (also for S1)

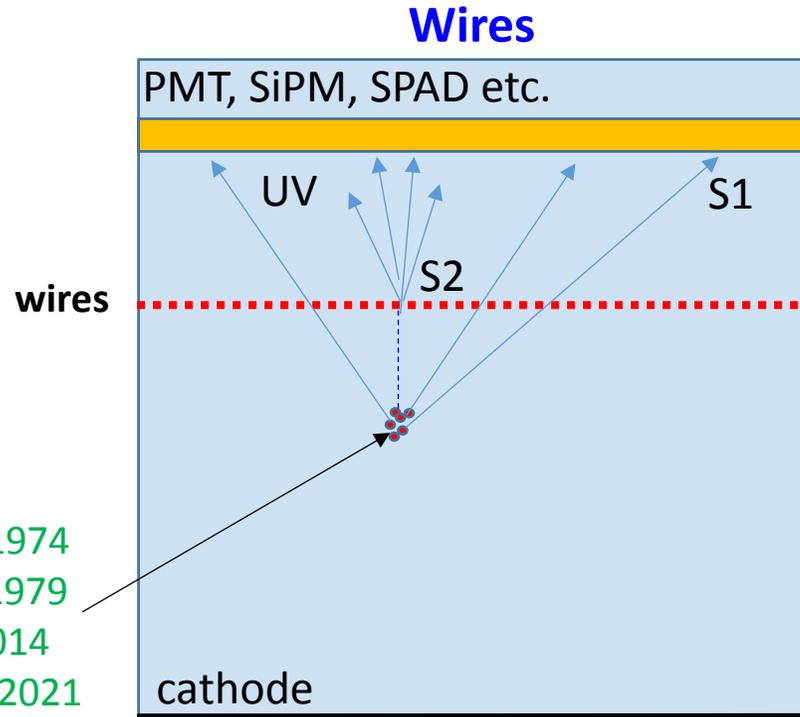
→ reduced dark-current issues → “cheaper” photo-sensors (SiPM, CMOS...)

→ lower detection thresholds



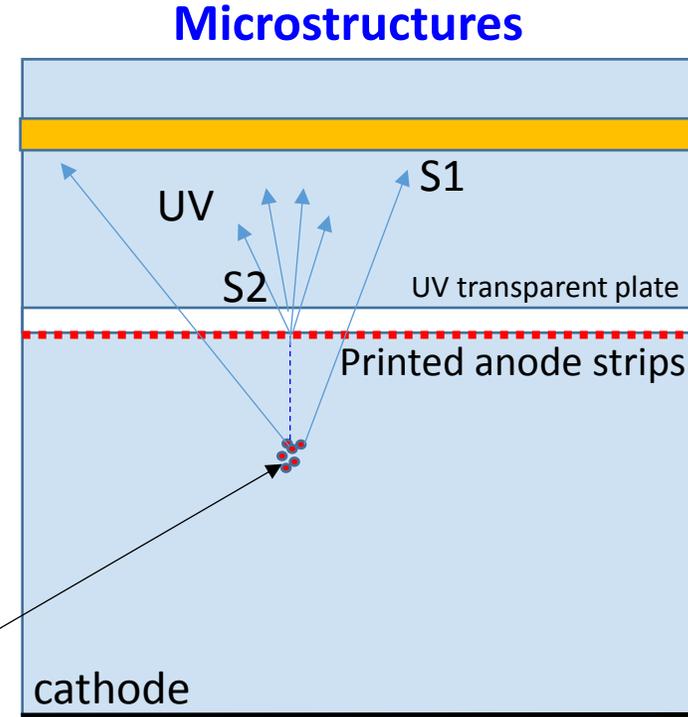
From wires to microstructures

Examples: here multiplier senses **S2 ONLY: EL & charge multiplication (CM)**

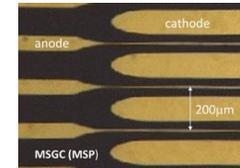


Wires in LXe:

Derenzo PRA 1974
Masuda NIM 1979
Aprile JINST 2014
Brown LIDINE 2021



**Microstrip plates
& more!**



Oed 1988

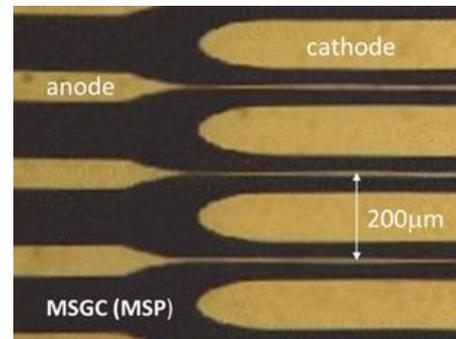
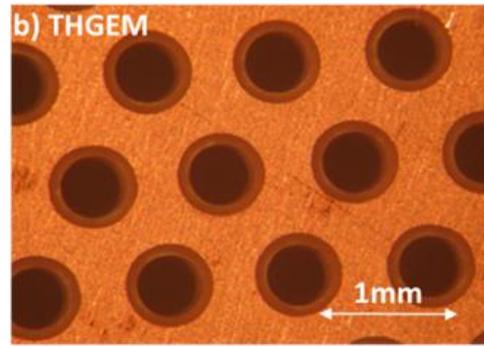
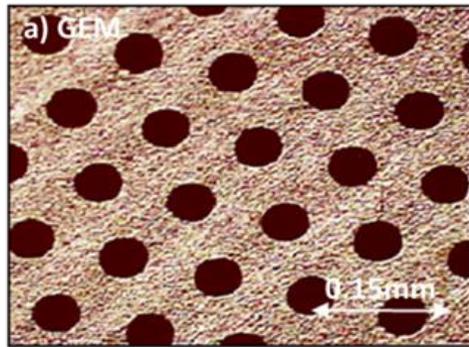
MSP LXe: **CM~10**

Policarpo et al. NIMA 1995

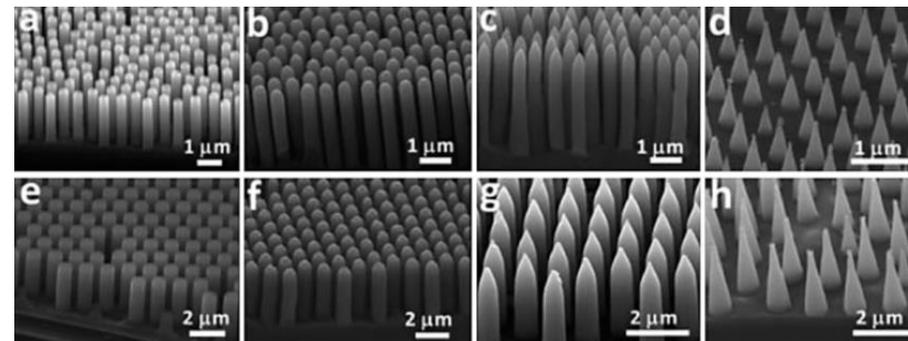
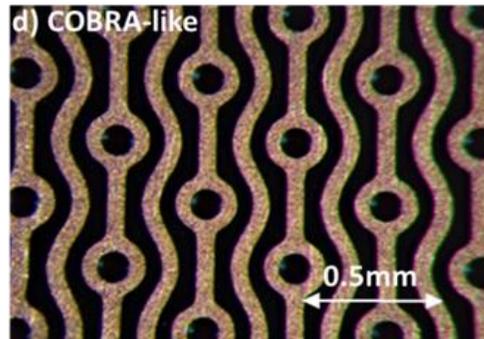
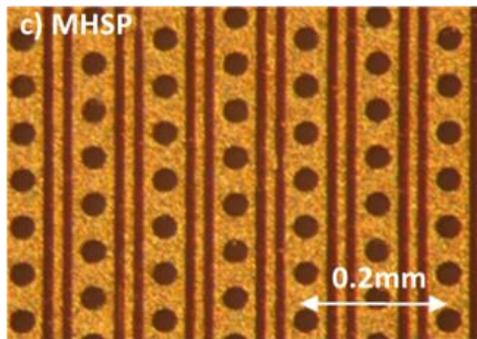
- Goals:**
- Devise other solutions than EL/CM (**S2**) on wires (sagging, staggering)
 - Search for robust **S2-e⁻ & S1-photon** recording modules

General idea: Micro-Patterned & Nanostructured electrodes

Make use of **known** and **yet unknown** electrodes to reach high photoyields:

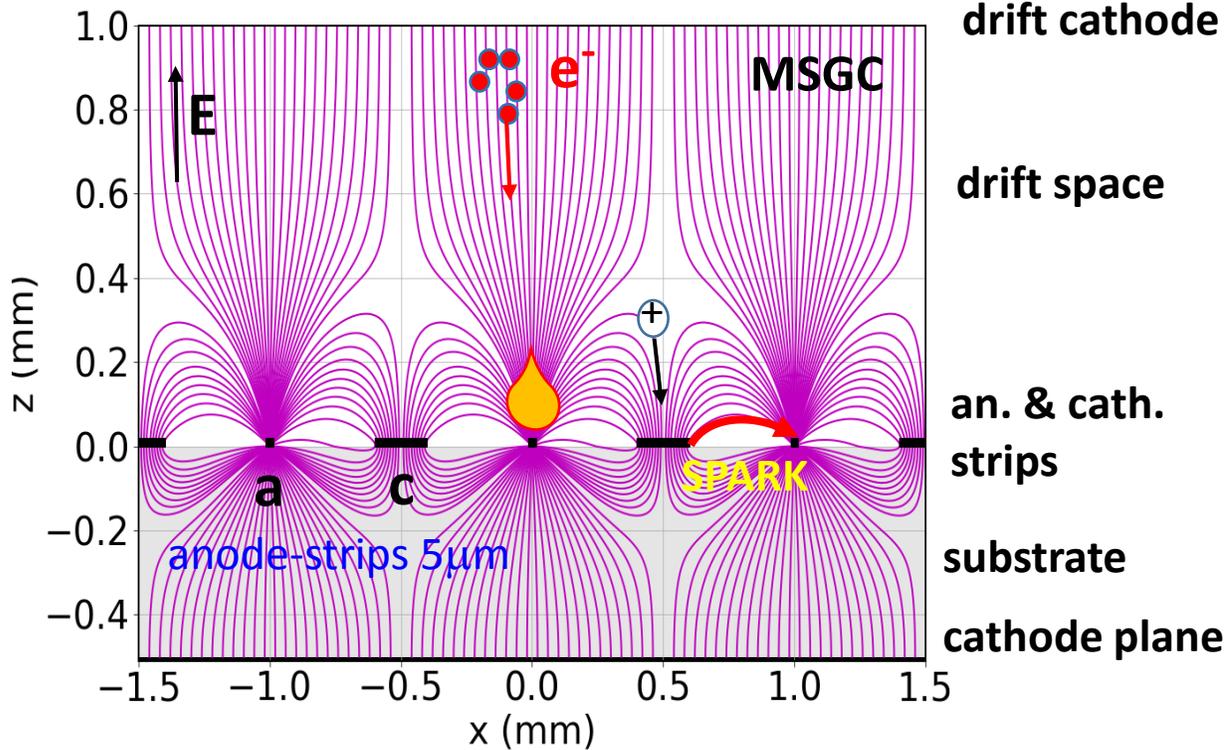


*SEM images of highly regular:
nanopillar, nanorod,
nanopencil & nanocone Si
arrays,
produced by wet-etching.*



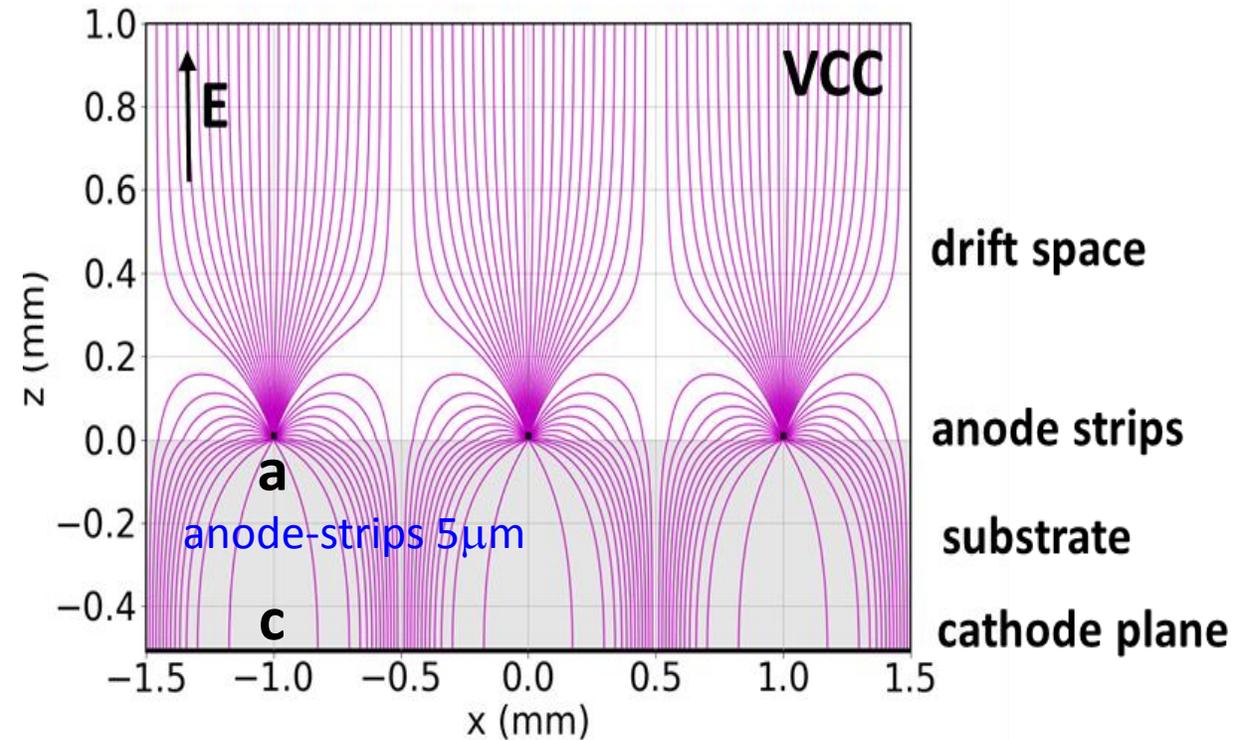
MSPs: MSGC & VCC

Microstrip Gas Chamber Oed 1988



Weakness: sparks a-c → limit HV

Virtual Cathode Chamber Capeans 1997

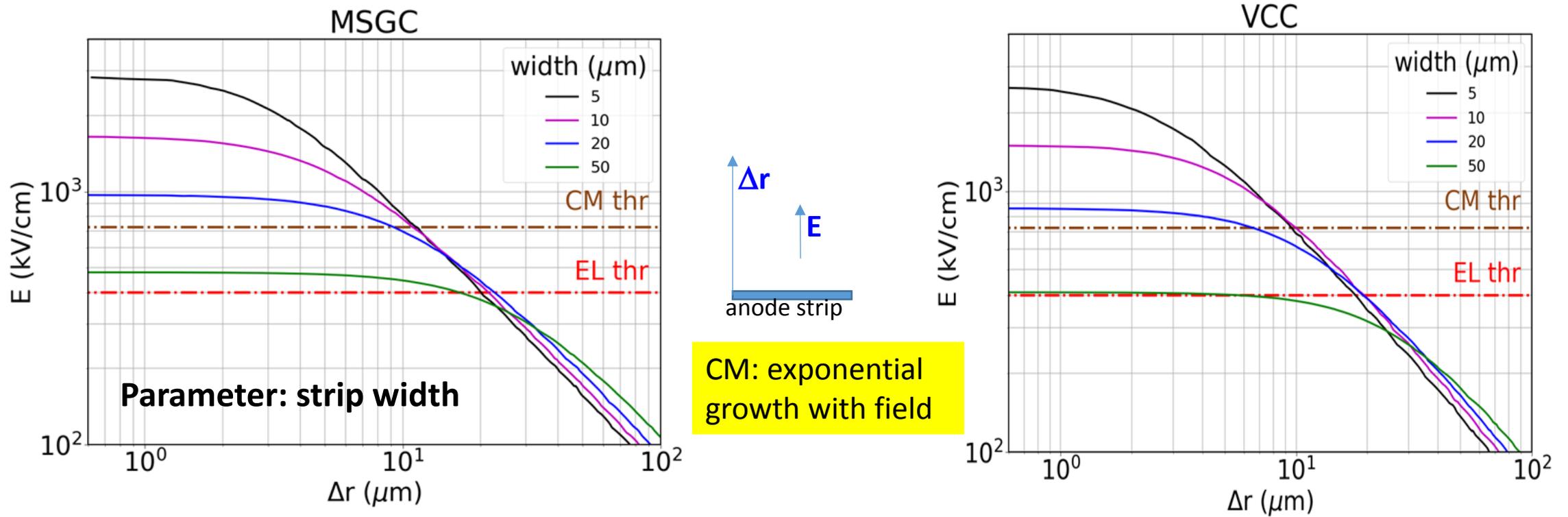


Benefit: spark-less.

The substrate separates strips from cathode plane

Field-line simulations: substrate 0.5mm; anode-strips 5 μ m; cathode-strips 200 μ m; drift-gap=1.9mm; strip pitch=1mm. Potentials: $V_a=5KV$; $V_c=0$; backplane: $V_b=0$; drift: $V_d=-300V$.

Simulated E vs distance from anode strip: MSGC vs VCC



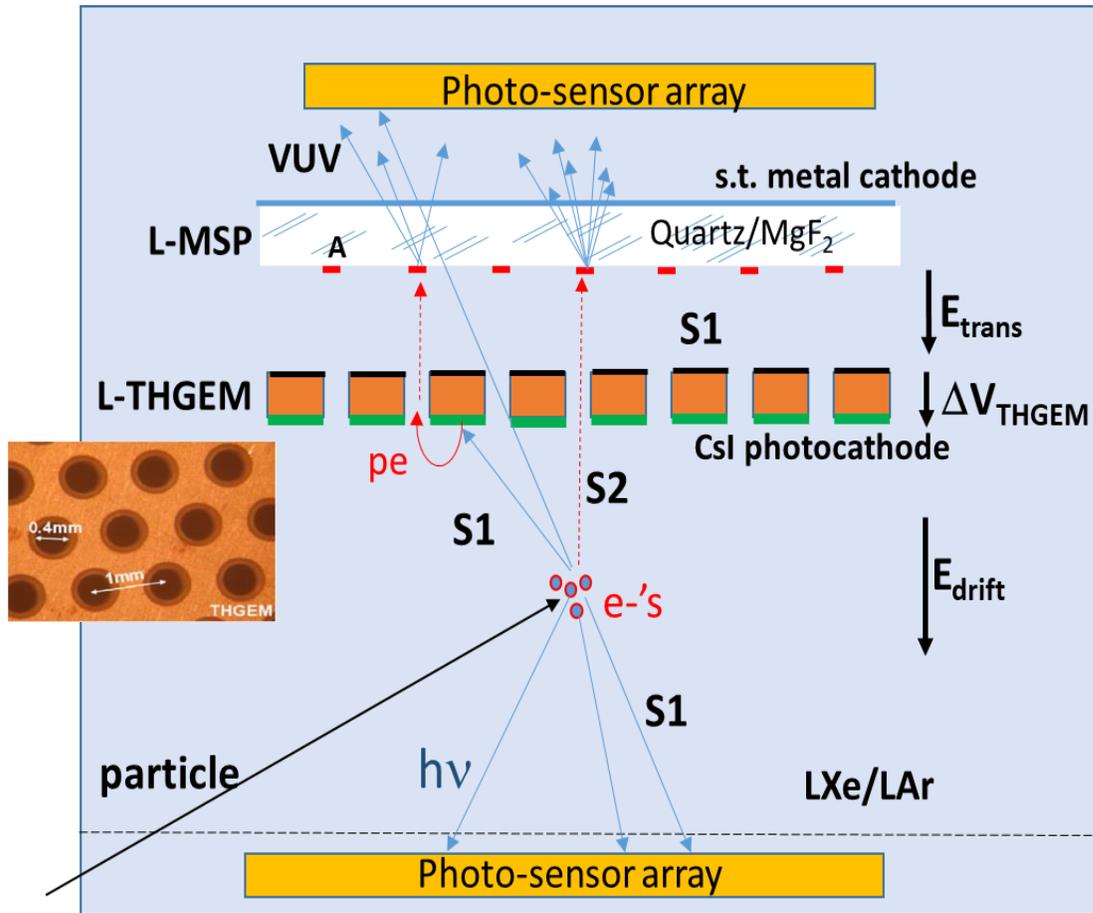
E vs distance from strip: substrate 0.5mm; anode-strips **5-50μm**; cathode-strips 200μm; drift-gap=1.9mm; strip pitch=1mm. Potentials: **V_a=5KV**; V_c=0; backplane: V_b=0; drift: V_d=-300V.

MSGC & VCC: ~same results but **5kV not applicable in MSGC (sparks)** → **V_a (VCC) > V_a (MSGC) !!!**
 → EL threshold ~ **20μm from strip surface**. CM threshold ~ **10μm from surface**. (thresholds: **Aprile 2014**)



Single-phase S1 & S2 - proposed concepts

Single-phase I: cascaded THGEM + MSP → S1 & S2

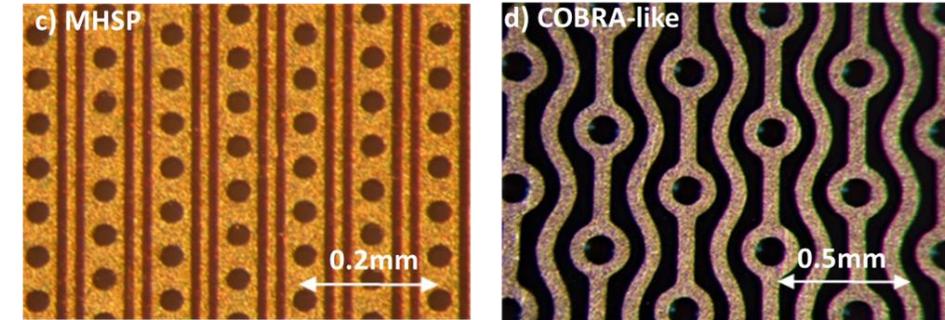
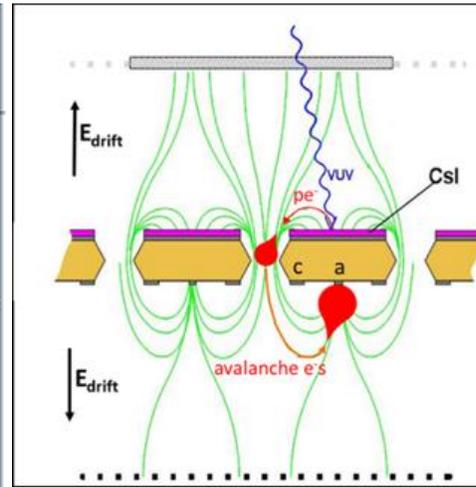
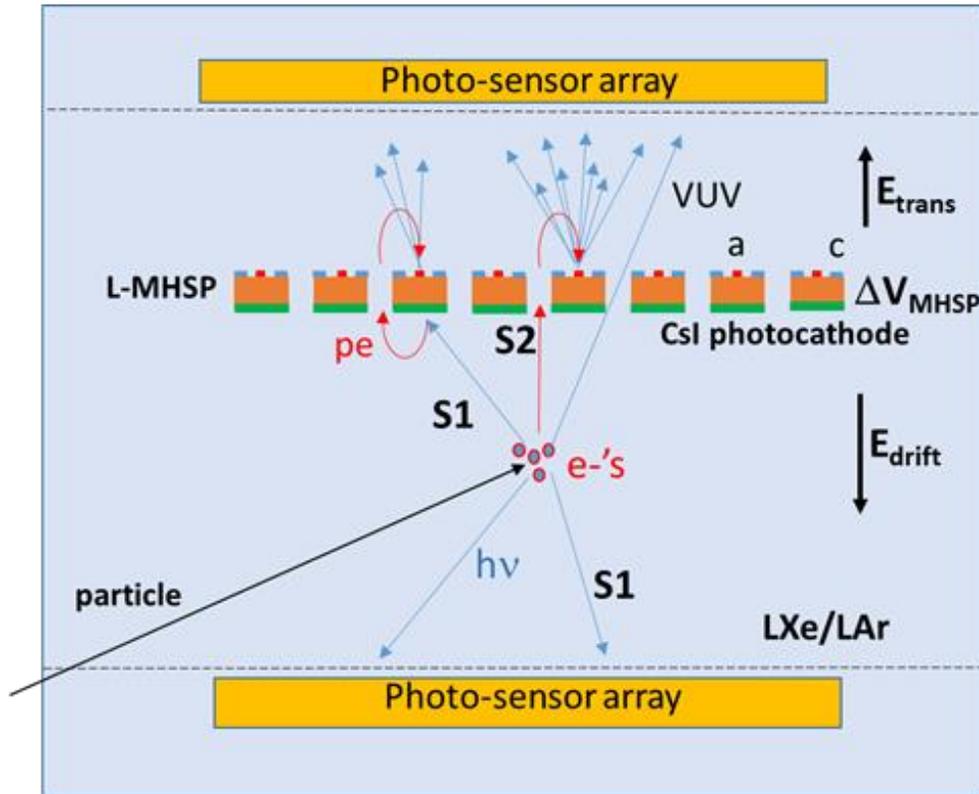


- Single-phase two-stage TPC with **CsI-coated L-THEM + L-MSP (here L-VCC)** strip multiplier;
- The L-VCC has semi-transparent Cr or Ni electrodes on VUV-transparent substrate.
- **S2 e- & S1 UV-pe (CsI)** are collected by L-THGEM holes and efficiently transferred to the L-VCC anode strips. **(MARTINEZ LEMA talk LIDINE22)**
- VUV photons from EL+small-avalanche near strips, are detected through the substrate.
- A fraction of S1 photons – are detected by bottom photo-sensors or reflected by a mirror-cathode (not shown) to the CsI.

CsI QE on perforated electrodes: about 25%

ERDAL 2021 https://jinst.sissa.it/jinst/theses/2021_JINST_TH_002.jsp

Single-phase II: Micro Hole & Strip Plate (MHSP) → S1 & S2

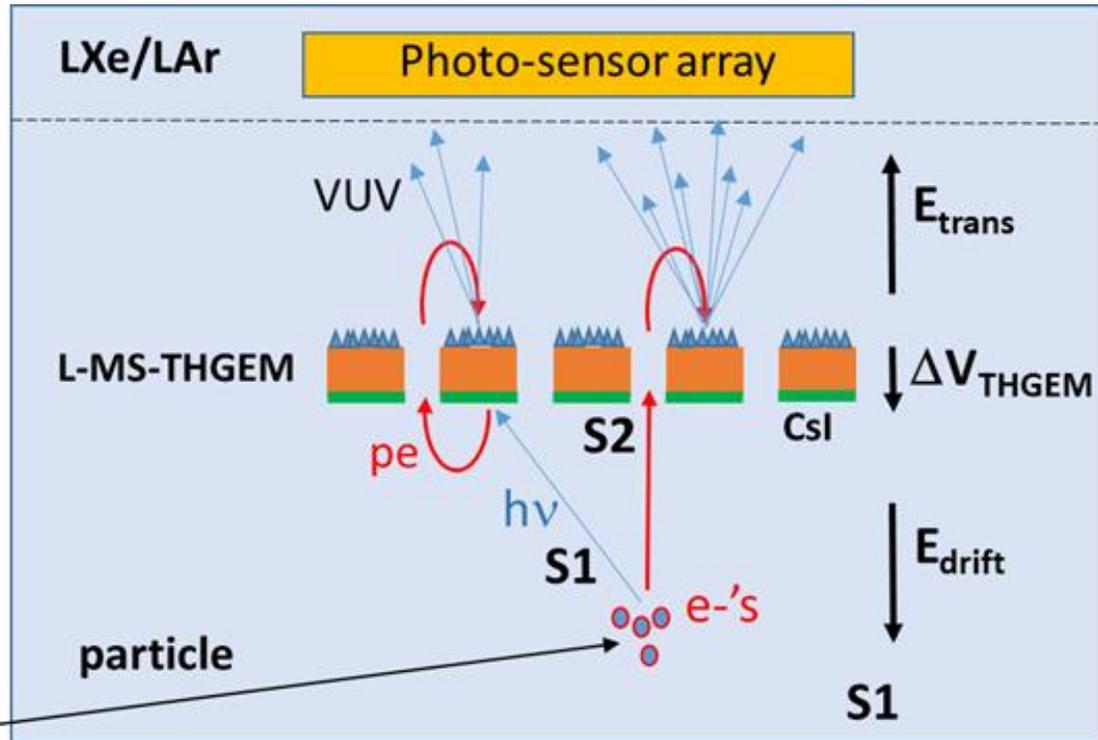


MHSP: Veloso, Rev Sci. Instr. 71, 2371 (2000)
<https://doi.org/10.1063/1.1150623>

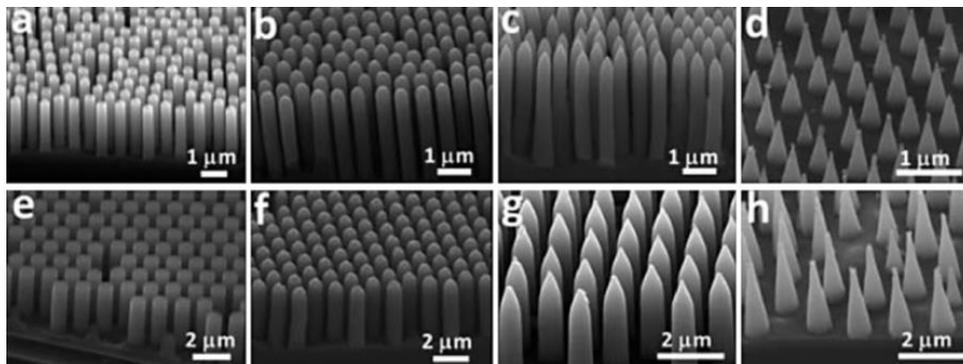
Current technologies → few- μ m strips

- A single-phase TPC with (here) a **CsI-coated L-MHSP**.
- Both S2 e^- & VUV photoelectrons are collected into the L-MHSP holes, drift to MHSP anode strips.
- VUV photons by EL + small avalanche near strips, are detected by the top photo-sensors.
- Other fraction of S1 photons - detected by bottom photo-sensors (or reflected by a mirror cathode).

Single-phase III: Micro-structured electrode → S1 & S2



- A single-phase TPC with a Liquid microstructure-coated THGEM multiplier (L-MS-THGEM) coated with CsI.
- Both S2 ionization electrons and S1 VUV photoelectrons are collected into the holes, drift across the THGEM electrode, towards the micro-structured top surface.
- VUV photons emitted by EL + small avalanche at the vicinity of the “anode tips”, are detected by the top photo-sensors.
- Other fraction of S1 photons are detected by bottom photo-sensors (or mirror)



Hao Lin <https://doi.org/10.1039/C3TA11889D>

Can we form large-size patterned electrodes?

ARIADNE LAr TPC with optical readout. 50x50cm² glass THGEM (GTHGEM)

Novel Glass THGEMs



16 50 cm x 50cm glass THGEMs

500 μ m hourglass shaped holes

- Glass THGEMs developed at Liverpool (Patent pending GB2019563.2):
 - Glass wafer/sheet with ITO coated electrode - holes produced using abrasive etching
 - Improvements to radiopurity/outgassing and gain uniformity compared to FR4
 - Robust and resistant to damage by discharges
 - GGEMs can be made from most types of glass and large areas are possible (towards 1m x 1m - glass dependent)

07/02/2022 K Mavrokoridis | ARIADNE+ | RD51 Meeting 22

- So far, borofloat 33 glass and fused silica glass electrodes (the latter of higher radio purity) produced by abrasive formation of sub-mm holes.
- Electrode surfaces coated by resistive ITO film;
- Can be patterned, by laser techniques – e.g. to form COBRA-like patterns.
- Thin strips and metallic patterns currently formed in industry: inkjet & photolithographic techniques. (few-micron thin strips on relatively large areas (up to 24" x 24") already formed on a variety of substrate materials.

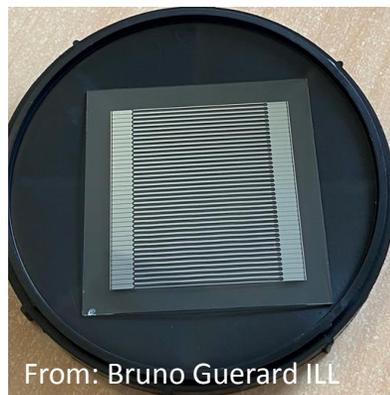
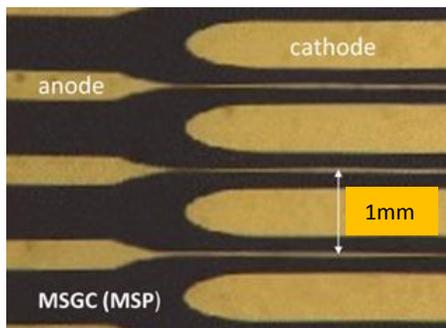
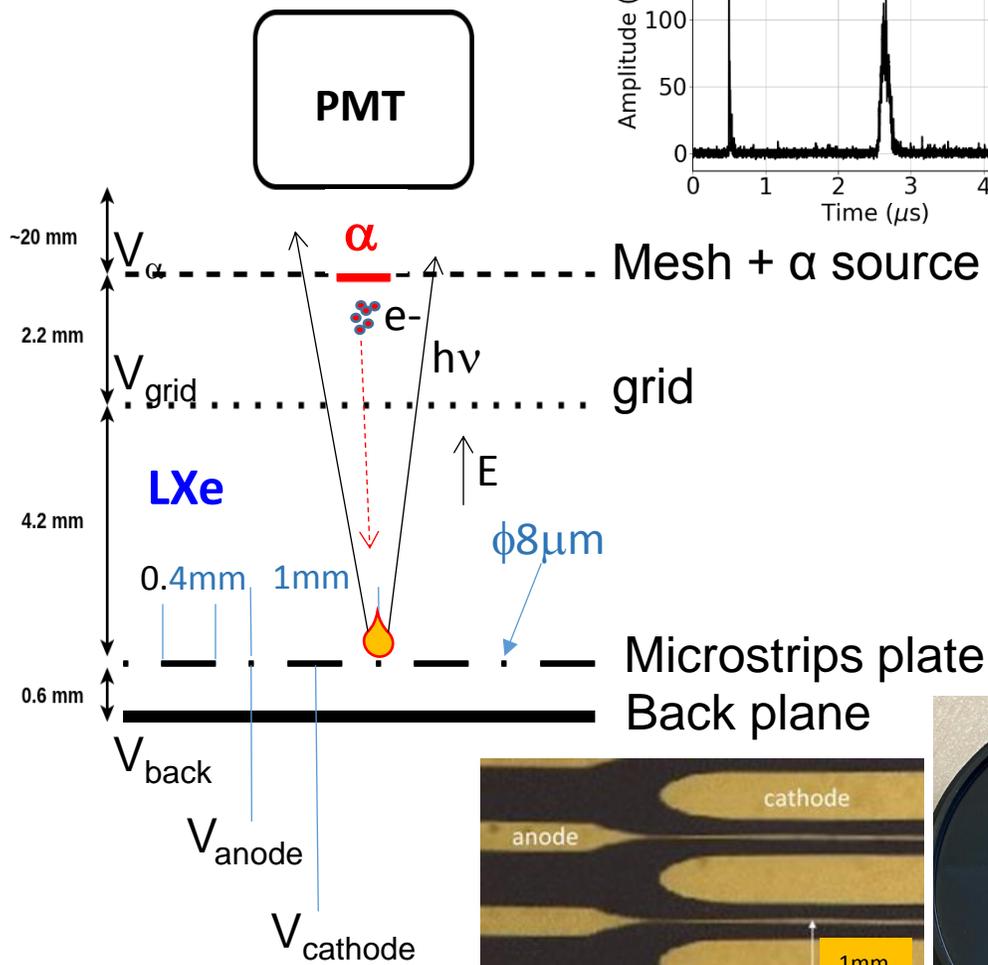
Lowe et al. Appl. Sci. 2021, 11(20), 9450;
<https://doi.org/10.3390/app11209450>

See refs in <https://doi.org/10.1088/1748-0221/17/08/P08002>

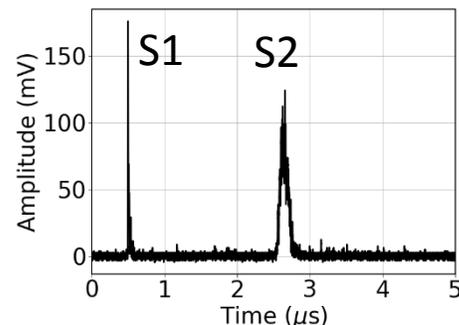
Very Preliminary results

Microstrip Plate - Preliminary results

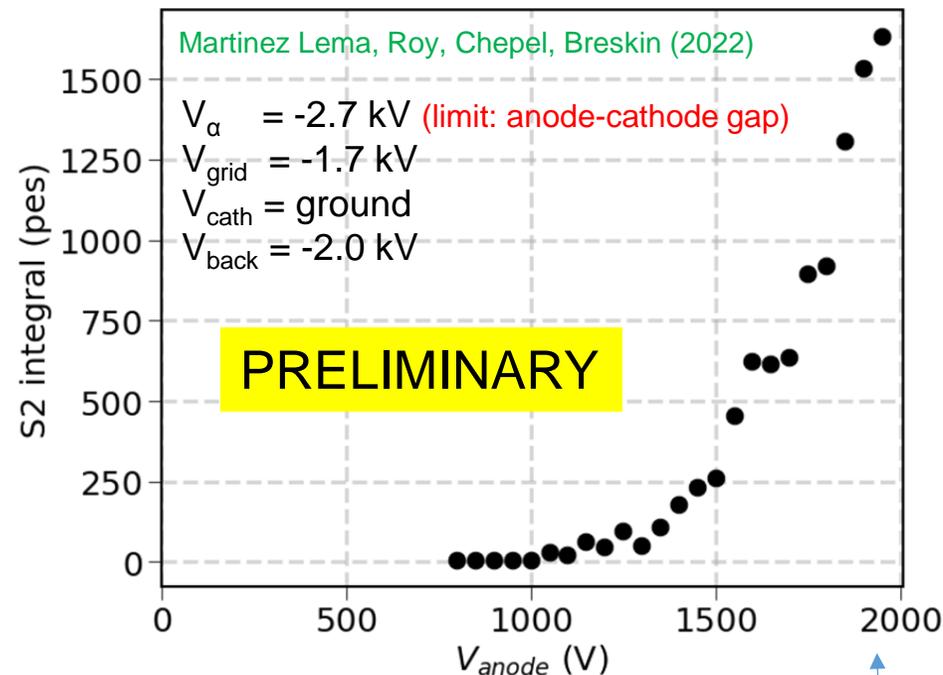
Setup



Single event



Average of S2 spectrum vs V_{anode}

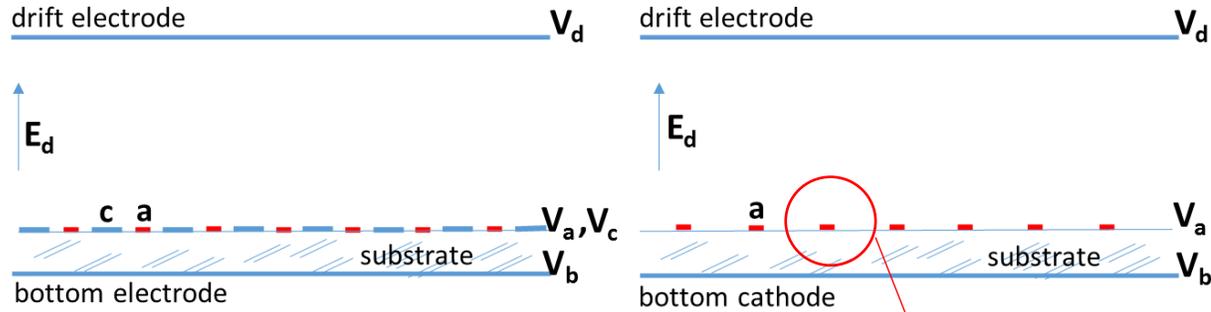


- $\Omega \sim 6\%$
- $T \sim 90\%$
- $QE \sim 40\%$
- $Q_{\text{total}}(\alpha) \sim 1$ fC
- $Y \sim 10$ photons/ e^-**

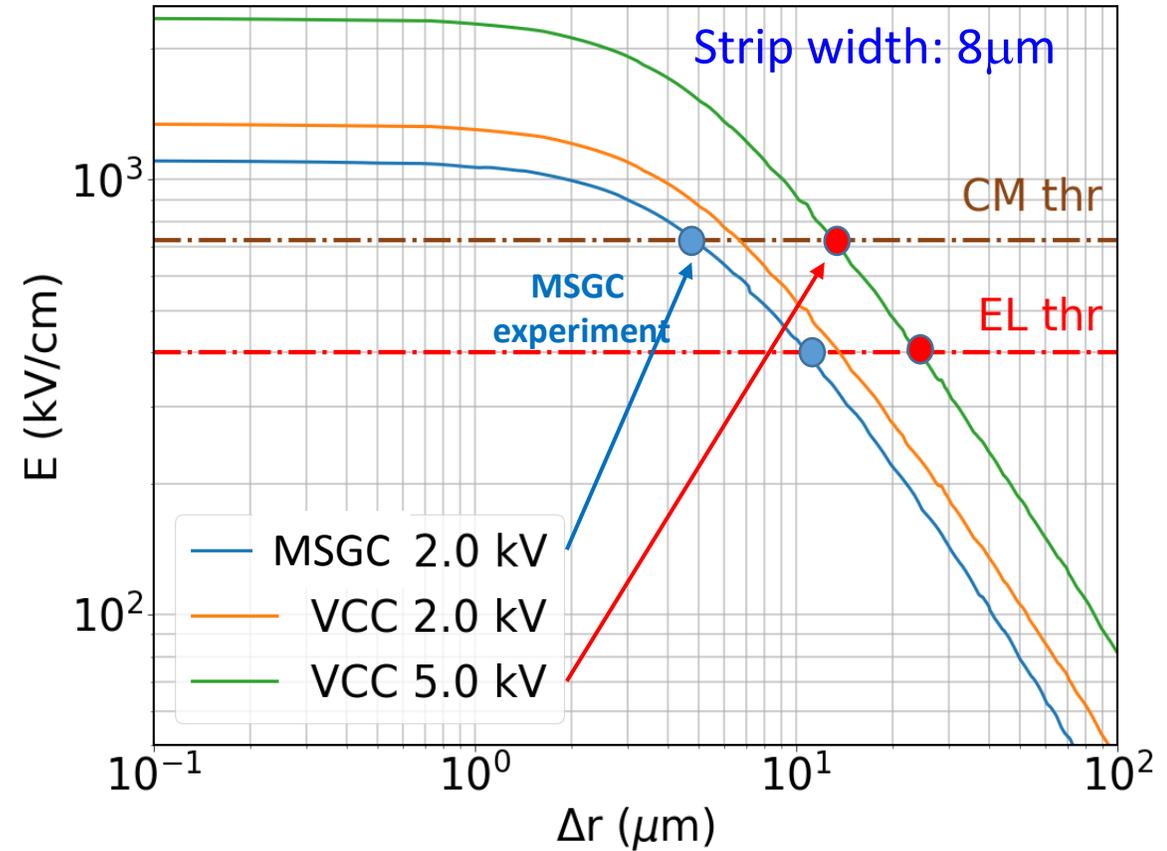
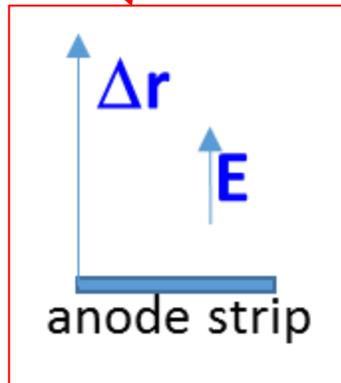
**Charge gain ~ 4
MSGC spark limit)**

Reminder:
MSP LXe: **CM ~ 10**
Policarpo et al. NIMA 1995

MSP Simulations - EL & CM onset vs distance from strip - vs V_a



Strip pitch 1 mm
 anode strip 8 μm
 Cathode strip (MSGC) 400 μm
 Substrate: 0.5 mm
 drift gap 4.2 mm
 V_d -2 kV
 V_b -2 kV
 V_c (in MSGC) 0 V
 V_a variable



MSGC: $V_a@2\text{kV}$: CM starts $\sim 4.8 \mu\text{m}$; EL $\sim 11 \mu\text{m}$
VCC: $V_a@5\text{kV}$: CM starts $\sim 15 \mu\text{m}$; EL $\sim 25 \mu\text{m}$

Summary & Status:

- New single-phase concepts combining micro-patterned strips, microstructures, hole-multipliers and VUV-photocathodes.
- Sensitive to e- & photons → S1 & S2
- High photoyields/e- expected → “easier” for photo-sensors (reduced dark-current issues)
- No “mechanical & electrostatic problems expected (e.g. as of wires)
- **Proof-of-principle**
 - MSGC **preliminary** photoyield ~ **10 photons/e** @ charge gain=4 (a-c HV limits)
- *Many open questions...*
- *Simulations & exp. R&D on MSPs configurations (LAr, LXe)*
- *Planned R&D on micro- & nanostructures*
- *Planned R&D on stability of VUV-photocathodes in noble liquids*
- *Sensor modules design (multiplier/photo-sensors)*
- **Open for collaborations**

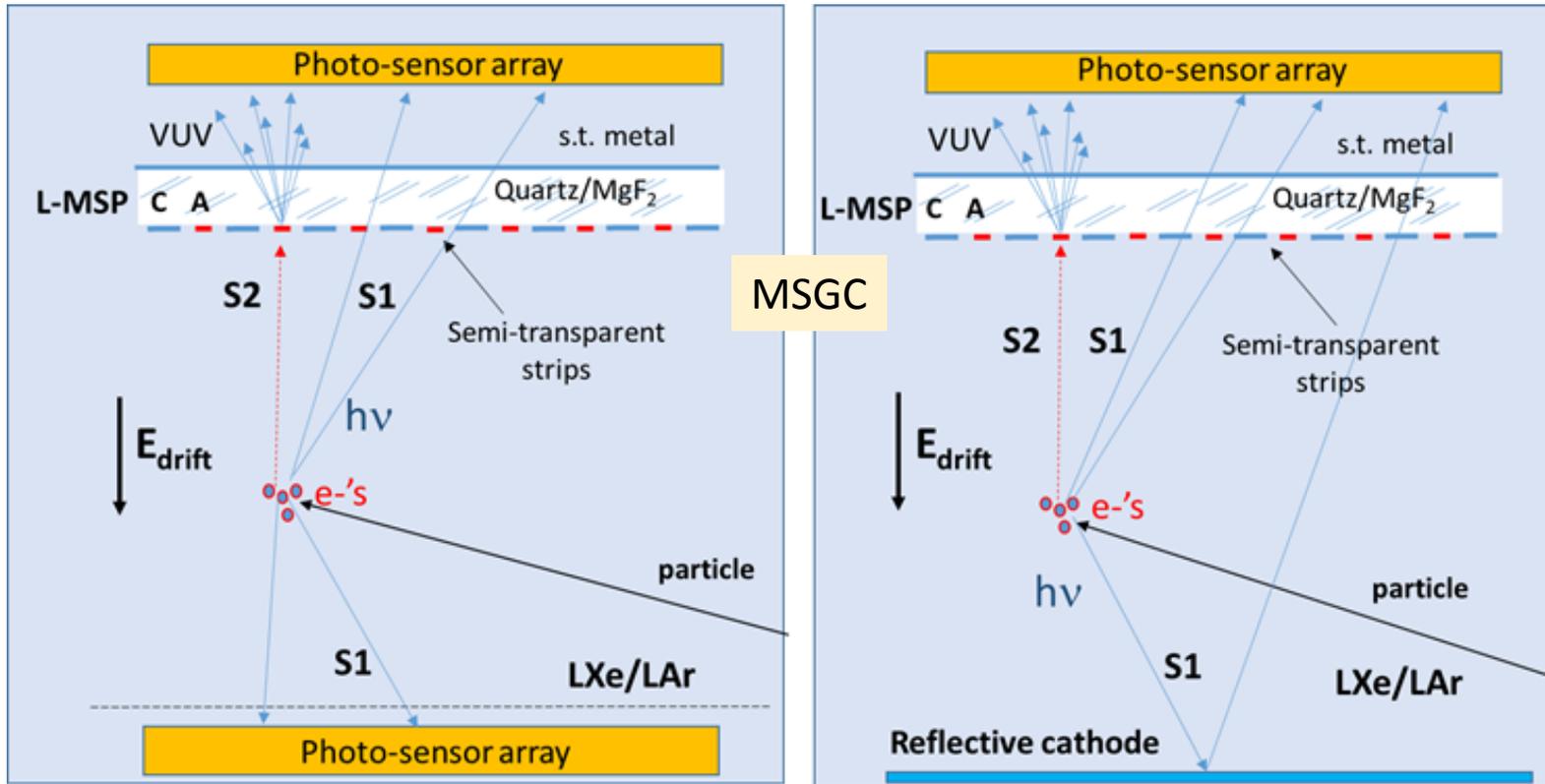
Thank you

Backup slides

Single-phase with Micro Strip Plates (MSP)

S2: EL+avalanche on strips. S2 Photons detected through VUV-transparent substrate

S1: photons detected (no amplification) by top and bottom photo-sensors (bottom can be replaced by mirror)

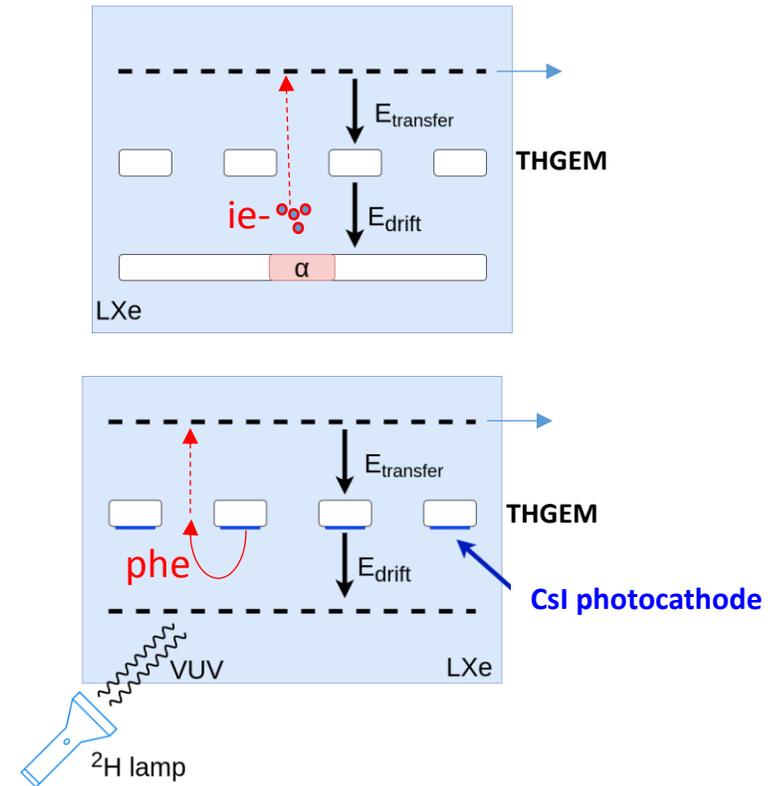
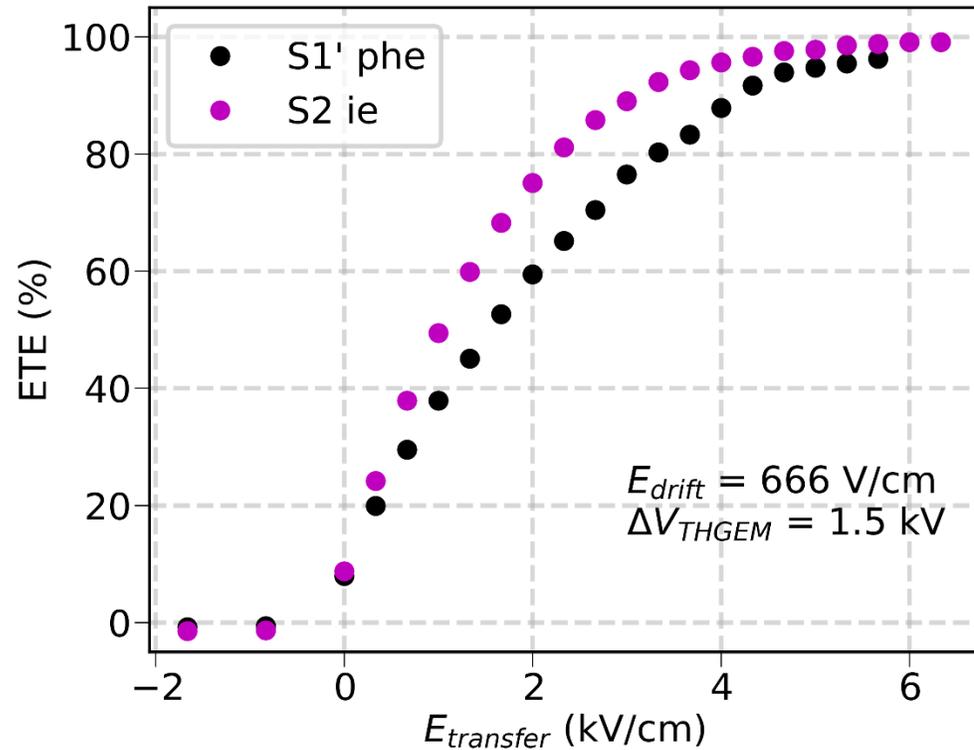


- MSP formed on VUV-transparent substrate, with thin Ni or Cr electrodes.
- **MSP: MSGC, VCC, others**
- Charges deposited in liquid, undergo EL & small CM at high field, near **anode strips**.
- The **effective light-emission region** function of MSP type, & potentials applied to electrodes.

Policarpo, x10 electron multiplication in LXe with MSGC NIMA 1995

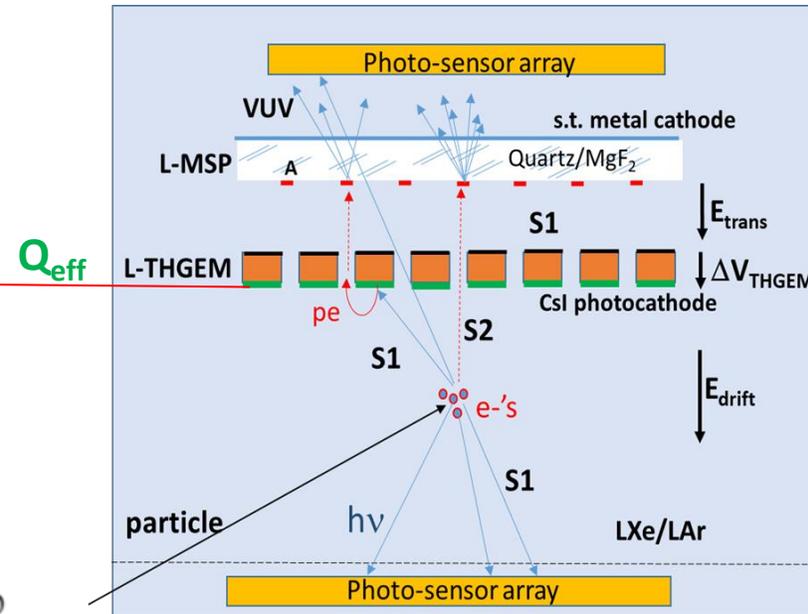
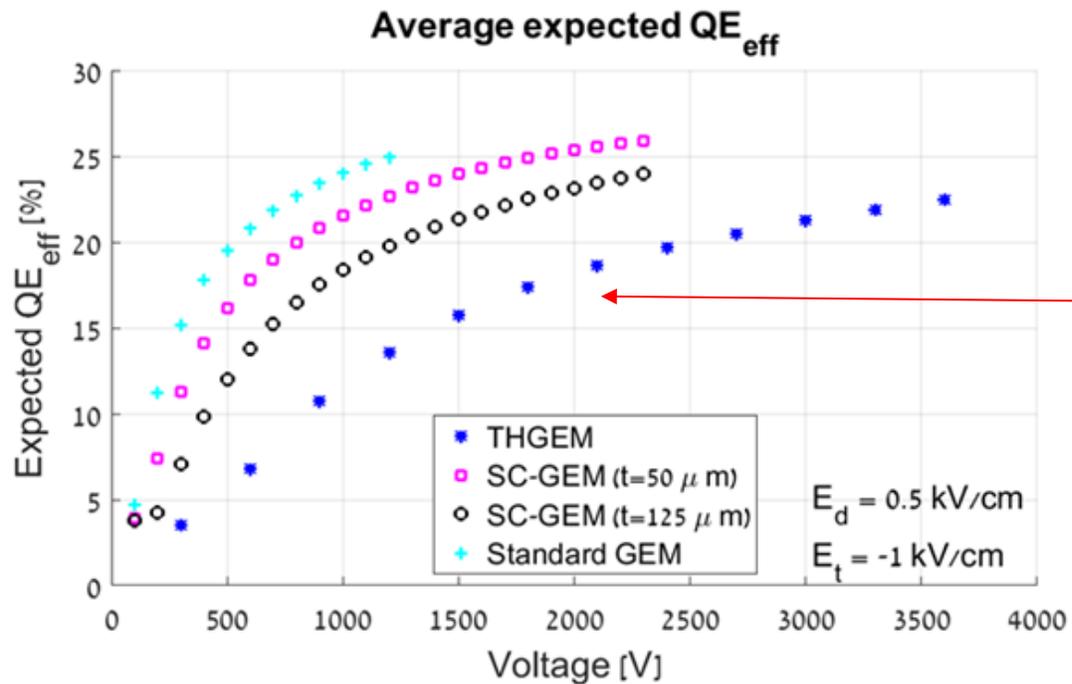
[https://doi.org/10.1016/0168-9002\(95\)00457-2](https://doi.org/10.1016/0168-9002(95)00457-2)

e- & pe- transfer through THGEM holes in LXe



Talk by Gonzalo Martinez Lema; LIDINE2022

Effective quantum efficiency Q_{eff} of CsI in LXe



ERDAL 2021 https://jinst.sissa.it/jinst/theses/2021_JINST_TH_002.jsp

Expected average Q_{eff} in LXe across the entire surface of an electrode, as a function of voltage across the electrode. They were computed (using COMSOL®) for different perforated electrodes; electric field values: $E_d=0.5 \text{ kV/cm}$ and $E_t=-1 \text{ kV/cm}$.